

30 V, dual P-channel Trench MOSFET Rev. 1 — 9 March 2012

Product data sheet

#### 1. **Product profile**

#### 1.1 General description

Dual P-channel enhancement mode Field-Effect Transistor (FET) in a small and leadless ultra thin SOT1118 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 1.2 Features and benefits

- Very fast switching
- Trench MOSFET technology
- 1.3 Applications
  - Charging switch for portable devices
  - DC/DC converters
  - Small brushless DC motor drive

- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Power management in battery-driven portables
- Hard disc and computing power management

#### 1.4 Quick reference data

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transi	stor						
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-30	V
V <sub>GS</sub>	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	<u>[1]</u>	-	-	-3.8	А
Static cha	racteristics (per transistor)						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 25 °C		-	70	87	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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### 2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1		54 50
2	G1	gate TR1	6 5 4	D1 D2
3	D2	drain TR2		
4	S2	source TR2	7 8	(」▙▆▓▓▖
5	G2	gate TR2		
6	D1	drain TR1	1 2 3	G1 S1 S2 G2
7	D1	drain TR1	Transparent top view	017aaa258
8	D2	drain TR2	SOT1118 (HUSON6)	

### 3. Ordering information

Table 3. Ordering in	nformation		
Type number	Package		
	Name	Description	Version
PMDPB70XP	HUSON6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1118

### 4. Marking

Table 4. Marking codes	
Type number	Marking code
PMDPB70XP	1H

### 5. Limiting values

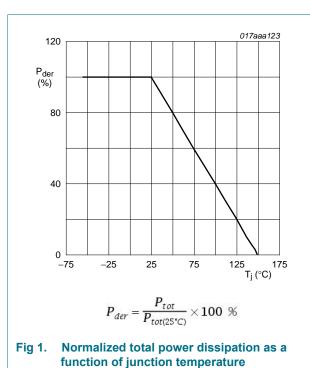
#### Table 5. Limiting values

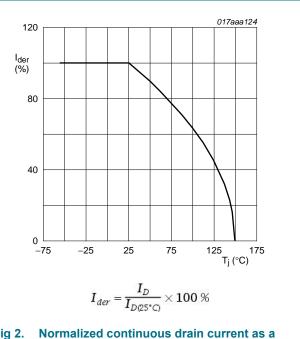
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per transist	or					
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	<u>[1]</u>	-	-3.8	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	<u>[1]</u>	-	-2.9	А
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	<u>[1]</u>	-	-1.9	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-11.6	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	490	mW
			[1]	-	1170	mW
		T <sub>sp</sub> = 25 °C		-	8300	mW
Source-drai	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	<u>[1]</u>	-	-1.2	А
Per device						
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

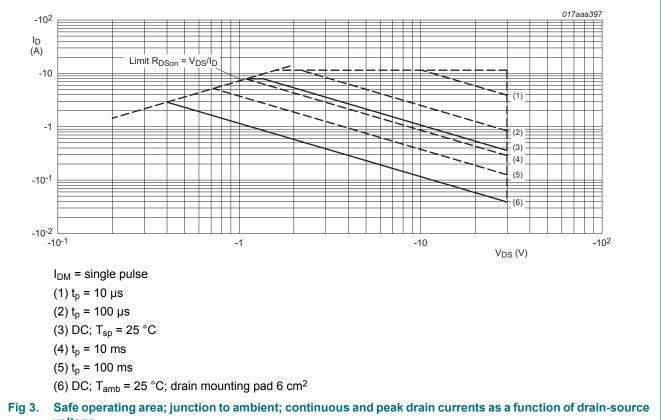






# **PMDPB70XP**

#### 30 V, dual P-channel Trench MOSFET



voltage

#### **Thermal characteristics** 6.

Symbol	Doromotor	Condition
Table 6.	Thermal characteristics	

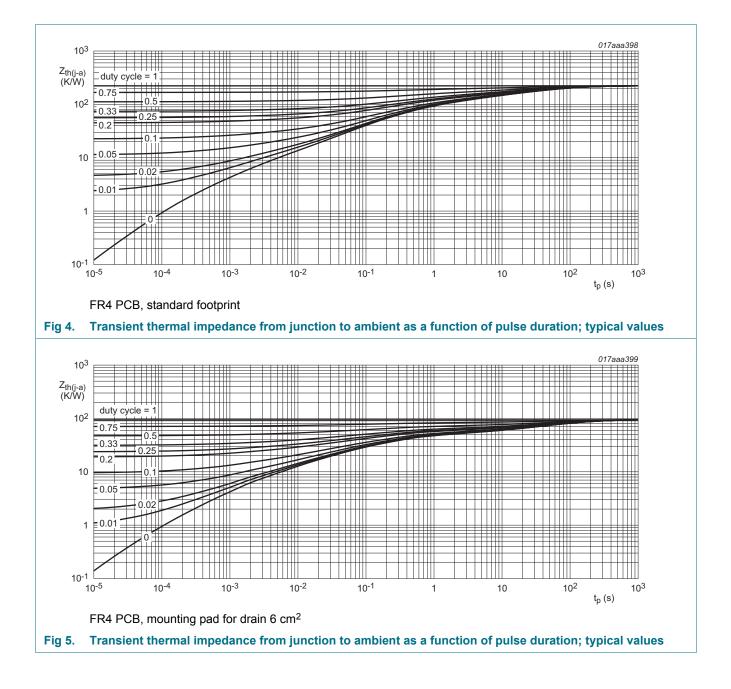
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
R <sub>th(j-a)</sub>	thermal resistance	in free air	<u>[1]</u>	-	223	256	K/W
	from junction to ambient		[2]	-	93	107	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	55	63	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	in free air		-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

# PMDPB70XP

#### 30 V, dual P-channel Trench MOSFET



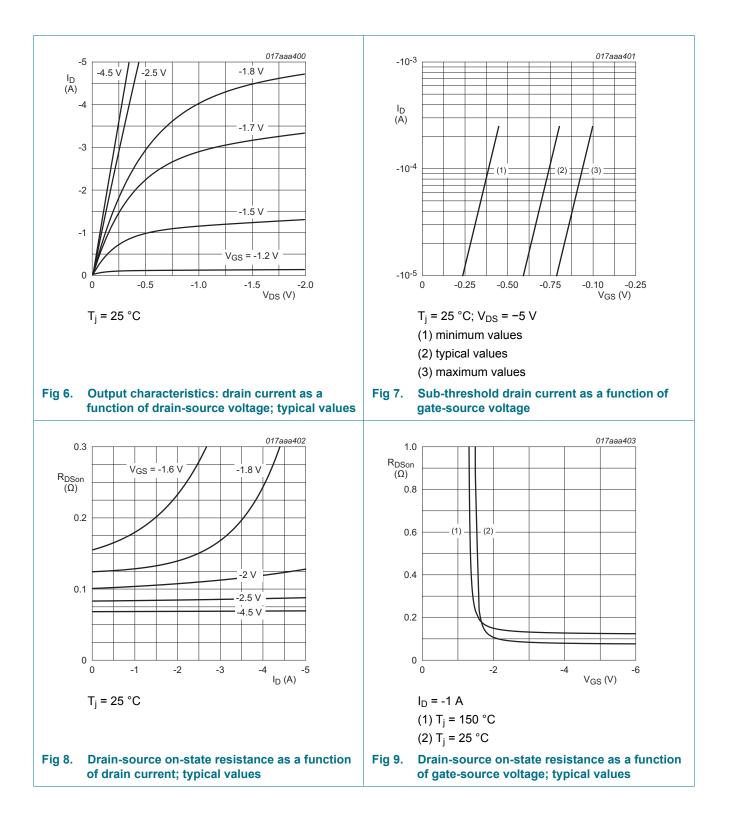
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### 7. Characteristics

	Characteristics			_		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics (per transistor)					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-30	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.45	-0.7	-1	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
		V <sub>DS</sub> = -30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	-10	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
		V <sub>GS</sub> = -12 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 25 °C	-	70	87	mΩ
	resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 150 °C	-	110	137	mΩ
		V <sub>GS</sub> = -2.5 V; I <sub>D</sub> = -1.6 A; T <sub>j</sub> = 25 °C	-	89	110	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = -10 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 25 °C	-	10	-	S
Dynamic c	haracteristics (per transist	or)				
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -15 V; $I_{D}$ = -2.9 A; $V_{GS}$ = -5 V;	-	5.2	7.8	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.1	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.95	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -15 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	680	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	54	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	40	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -15 V; I <sub>D</sub> = -2.9 A; V <sub>GS</sub> = -5 V;	-	3	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C	-	15	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	112	-	ns
t <sub>f</sub>	fall time		-	48	-	ns
Source-dra	ain diode (per transistor)					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1.2 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.8	-1.2	V

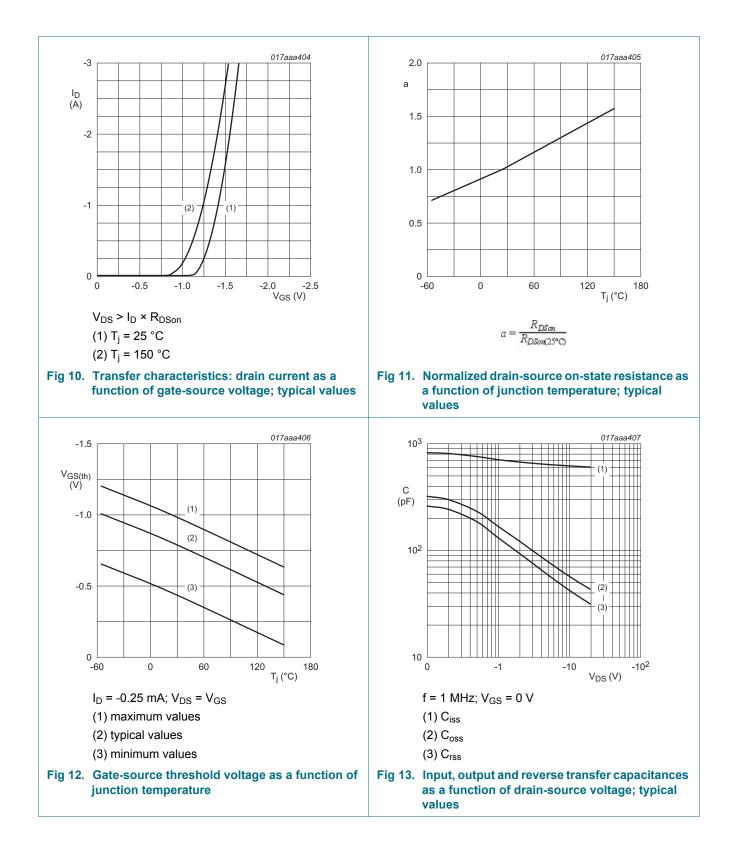
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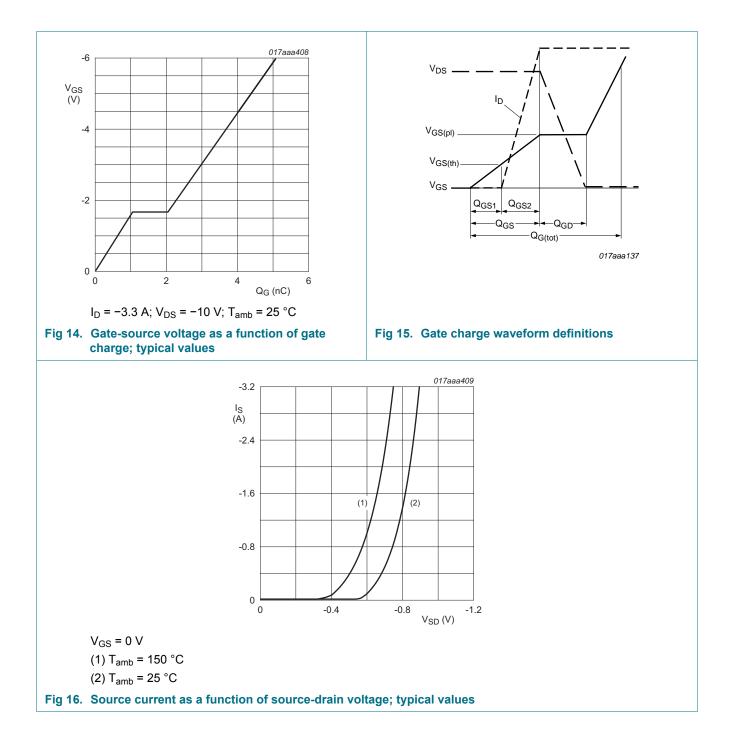
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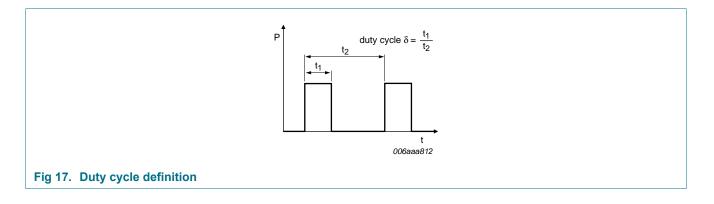
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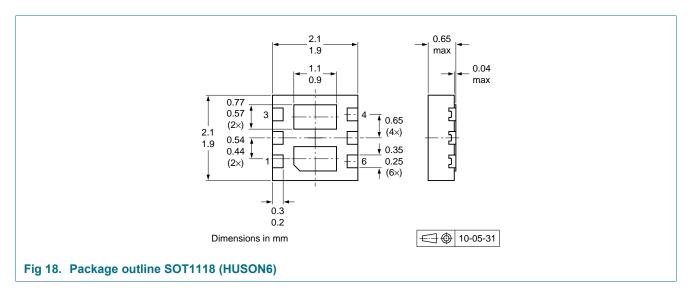
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### 8. Test information

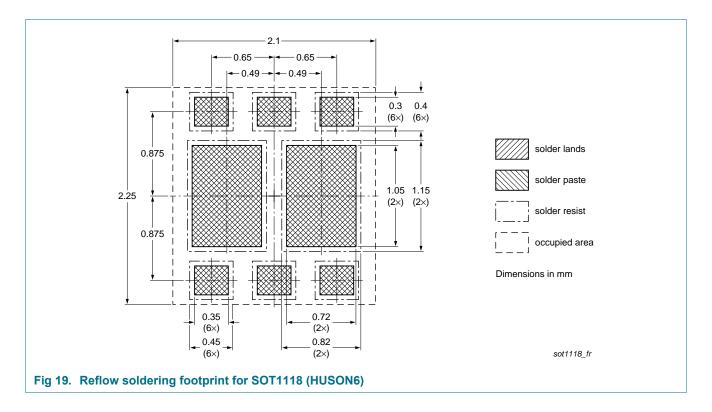


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### 9. Package outline



### 10. Soldering



#### 30 V, dual P-channel Trench MOSFET

### **11. Revision history**

Table 8. Revisio	Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
PMDPB70XP v.1	20120309	Product data sheet	-	-	

### 12. Legal information

#### 12.1 Data sheet status

Document status <sup>[1]</sup> <sup>[2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

[2] The term 'short data sheet' is explained in section "Definitions'

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#### 30 V, dual P-channel Trench MOSFET

### 14. Contents

1	Product profile1
1.1	General description1
1.2	Features and benefits1
1.3	Applications1
1.4	Quick reference data1
2	Pinning information2
3	Ordering information2
4	Marking
5	Limiting values
6	Thermal characteristics4
7	Characteristics6
8	Test information10
9	Package outline11
10	Soldering11
11	Revision history12
12	Legal information13
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks14
13	Contact information14

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